ROHS COMPLIANT

HALOGEN

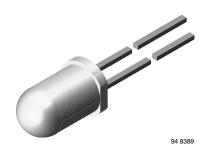
FREE

GREEN (5-2008)



Vishay Semiconductors

High Power Infrared Emitting Diode, 940 nm, GaAlAs, MQW



DESCRIPTION

TSAL6100 is an infrared, 940 nm emitting diode in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed molded in a blue-gray plastic package.

FEATURES

- · Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Peak wavelength: $\lambda_p = 940 \text{ nm}$
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity: $\phi = \pm 10^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Infrared remote control units with high power reqirements
- Free air transmission systems
- Infrared source for optical counters and card readers
- IR source for smoke detectors

PRODUCT SUMMARY

COMPONENT	I _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)
TSAL6100	170	± 10	940	15

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TSAL6100	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾	

Note

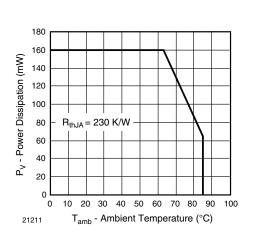
• MOQ: minimum order quantity

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	5	V
Forward current		١ _F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	1.5	A
Power dissipation		Pv	160	mW
Junction temperature		Тj	100	°C
Operating temperature range		T _{amb}	-40 to +85	°C
Storage temperature range		T _{stg}	-40 to +100	°C
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm soldered on PCB	R _{thJA}	230	K/W

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Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

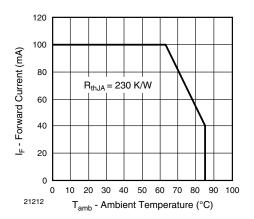


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.35	1.6	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.2	3	V
Temperature coefficient of V_F	I _F = 1 mA	TK _{VF}		-1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		40		pF
	I _F = 100 mA, t _p = 20 ms	l _e	80	170	400	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e	650	1450		mW/sr
Radiant power	I _F = 100 mA, t _p = 20 ms	фе		40		mW
Temperature coefficient of ϕ_{e}	I _F = 20 mA	ΤKφ _e		-0.6		%/K
Angle of half intensity		φ		± 10		deg
Peak wavelength	l _F = 100 mA	λρ		940		nm
Spectral bandwidth	l _F = 100 mA	Δλ		30		nm
Temperature coefficient of λ_p	l _F = 100 mA	ΤΚλρ		0.2		nm/K
Rise time	I _F = 100 mA	t _r		15		ns
Fall time	I _F = 100 mA	t _f		15		ns

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

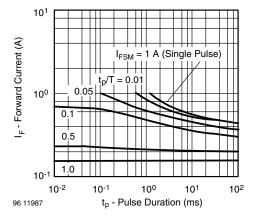


Fig. 3 - Pulse Forward Current vs. Pulse Duration

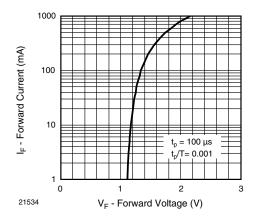


Fig. 4 - Forward Current vs. Forward Voltage

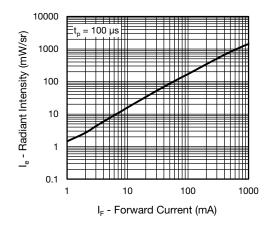


Fig. 5 - Radiant Intensity vs. Forward Current

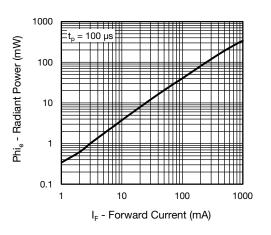


Fig. 6 - Radiant Power vs. Forward Current

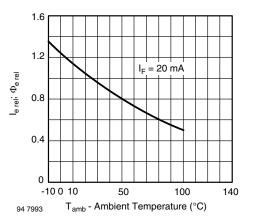


Fig. 7 - Rel. Radiant Intensity/Power vs. Ambient Temperature

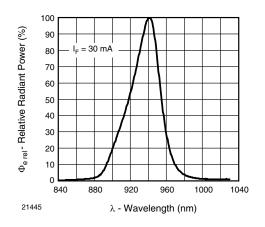


Fig. 8 - Relative Radiant Power vs. Wavelength

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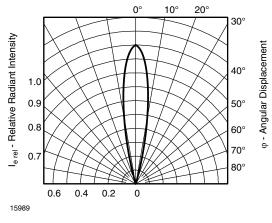
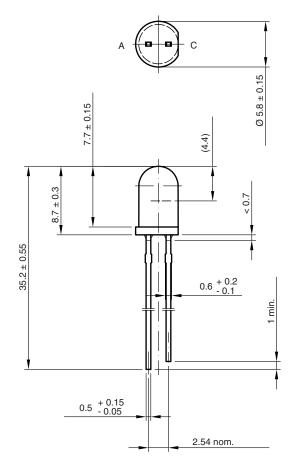
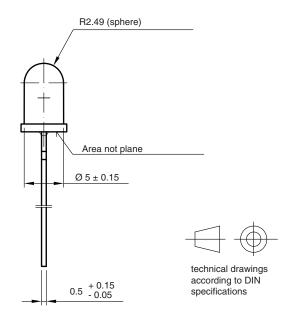


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters





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